

Aliases (C0603S222K1RAC7867)

General Information

Series

Style Description

Features

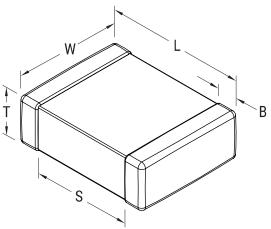
SMD Comm X7R FE, Ceramic, 2,200 pF, 10%, 100 VDC, X7R, SMD, MLCC, FE-CAP, Floating Electrode, Temperature Stable, 0603, 0.5 mm

SMD Comm X7R FE

SMD, MLCC, FE-CAP, Floating Electrode, Temperature Stable

FE-CAP, Floating Electrode,

SMD Chip



	Click here for the 3D model.	В	reduces	Temperature Stable
			RoHS	Yes
			Termination	Tin
			Marking	No
			AEC-Q200	No
			Typical Component Weight	4.8 mg
			Shelf Life	78 Weeks
			MSL	1
	Dimensions		Specifications	
	Chip Size 0603		Capacitance	2,200 pF
	L 1.6mm +/-0.15mm		Measurement Condition	1 kHz 1.0Vrms

В	0.35mm +/-0.15mm	
Packaging Specifications		
Packaging	T&R, 180mm, Paper Tape	

4000

0.8mm +/-0.15mm

0.8mm +/-0.07mm

0.5mm MIN

W

Т

S

Packaging Quantity

Specifications	
Capacitance	2,200 pF
Measurement Condition	1 kHz 1.0Vrms
Tolerance	10%
Voltage DC	100 VDC
Dielectric Withstanding Voltage	250 VDC
Temperature Range	-55/+125°C
Temp. Coefficient	X7R
Capacitance Change with Reference to +25°C and 0 VDC Applied (TCC)	15%, 1kHz 1.0Vrms
Dissipation Factor	2.5% 1 kHz 1.0Vrms
Aging Rate	3% Loss/Decade Hour: Referee Time is 1000 Hours
Insulation Resistance	100 GOhms

Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute - and we specifically disclaim - any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.

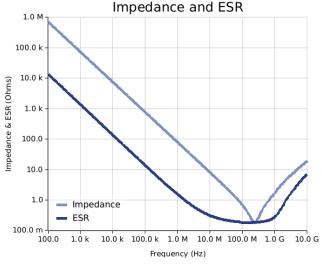
Generated 06/28/2025 © 2006 - 2025 YAGEO

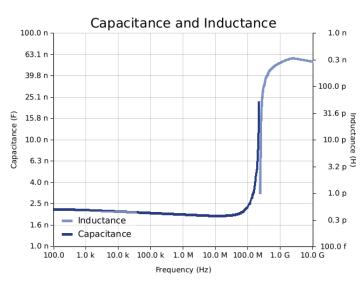


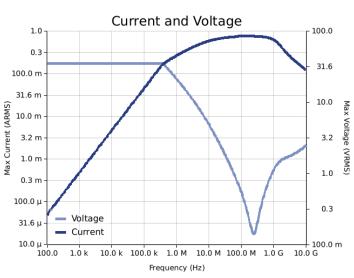
Aliases (C0603S222K1RAC7867) SMD Comm X7R FE, Ceramic, 2,200 pF, 10%, 100 VDC, X7R, SMD, MLCC, FE-CAP, Floating Electrode, Temperature Stable, 0603, 0.5 mm

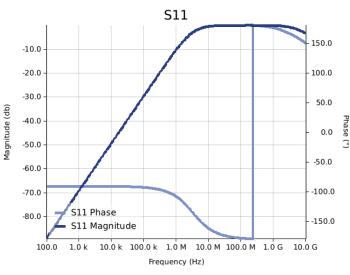
Simulations

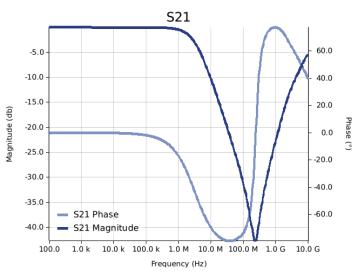
For the complete simulation environment please visit K-SIM.

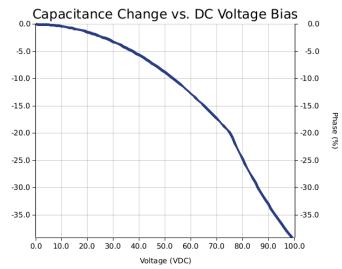








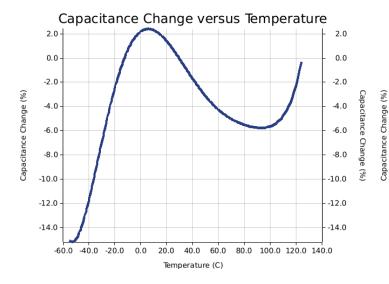


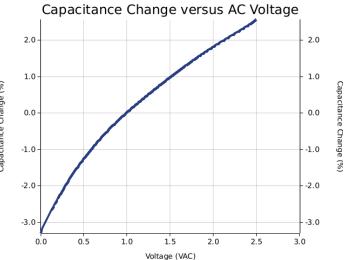


Generated 06/28/2025 © 2006 - 2025 YAGEO



Aliases (C0603S222K1RAC7867) SMD Comm X7R FE, Ceramic, 2,200 pF, 10%, 100 VDC, X7R, SMD, MLCC, FE-CAP, Floating Electrode, Temperature Stable, 0603, 0.5 mm





Generated 06/28/2025 © 2006 - 2025 YAGEO



Aliases (C0603S222K1RAC7867) SMD Comm X7R FE, Ceramic, 2,200 pF, 10%, 100 VDC, X7R, SMD, MLCC, FE-CAP, Floating Electrode, Temperature Stable, 0603, 0.5 mm

These are simulations.

This is not a specification!

The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

The responses shown do not represent a specified or implied maximum capability of the device for all applications.

- The ESR used for ripple "Ripple Current/Voltage vs. Frequency" plots is the ESR at ambient temperature.

- The ESR in the "Temperature Rise vs. Ripple Current" plots is adjusted to each incremental temperature rise before the power and ripple current is calculated. The effects shown herein are based on measured data from a multiple part sample of the parts in question.

 Ripple capability of this device will be factored by thermal resistance (Rth) created by circuit traces (addi affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

 The peak voltages generated in the "Temperature Rise vs. Combined Ripple Currents" plot are calculated for each frequency and are not combined with voltages
- generated at any other harmonics.

 Please consult with the catalog or field applications engineer for maximum capability of the device in specific applications.

All product information and data (collectively, the "Information") are subject to change without notice.

KEMET K-SIM is designed to simulate behavior of components with respect to frequency, ambient temperature, and DC bias levels. The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation effects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

All Information given herein is believed to be accurate and reliable, but is presented without guarantee, warranty, or responsibility of any kind, expressed or implied. Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute – and we specifically disclaim – any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.

If you have any questions please contact K-SIM.

Generated 06/28/2025 © 2006 - 2025 YAGEO